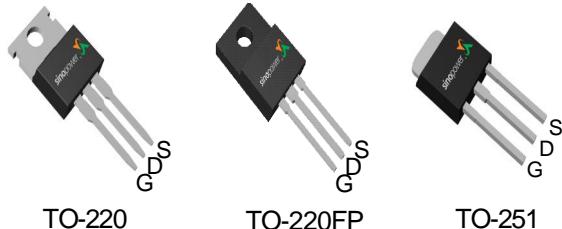


N-Channel Enhancement Mode MOSFET

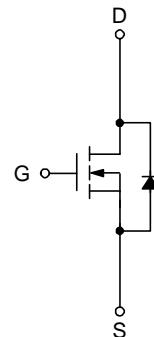
Features

- 600V/11A,
 $R_{DS(ON)} = 0.36\Omega$ (max.) @ $V_{GS} = 10V$
 $V_{DS} @ T_j$, max=700V (typ.)
- Reliable and Rugged
- Avalanche Rated
- Lead Free and Green Devices Available
(RoHS Compliant)
- 100% UIS + R_g Tested

Pin Description



TO-220 TO-220FP TO-251

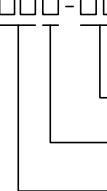


N-Channel MOSFET

Applications

- AC/DC Power Conversion in Switched Mode Power Supplies (SMPS).
- Uninterruptible Power Supply (UPS),
- Adapter.

Ordering and Marking Information

SM6A25NS  -  <ul style="list-style-type: none"> Assembly Material Handling Code Temperature Range Package Code 	Package Code F : TO-220 FP : TO-220FP UB : TO-251 Operating Junction Temperature Range C : -55 to 150 °C Handling Code TU : Tube Assembly Material G : Halogen and Lead Free Device
SM6A25NS F/FP/UB :  XXXXX	XXXXX - Lot Code

Note: SINOPOWER lead-free products contain molding compounds/die attach materials and 100% matte tin plate termination finish; which are fully compliant with RoHS. SINOPOWER lead-free products meet or exceed the lead-free requirements of IPC/JEDEC J-STD-020D for MSL classification at lead-free peak reflow temperature. SINOPOWER defines "Green" to mean lead-free (RoHS compliant) and halogen free (Br or Cl does not exceed 900ppm by weight in homogeneous material and total of Br and Cl does not exceed 1500ppm by weight).

SINOPOWER reserves the right to make changes to improve reliability or manufacturability without notice, and advise customers to obtain the latest version of relevant information to verify before placing orders.

Absolute Maximum Ratings

Symbol	Parameter	Rating	Unit
Common Ratings ($T_A=25^\circ\text{C}$ Unless Otherwise Noted)			
V_{DSS}	Drain-Source Voltage	600	V
V_{GSS}	Gate-Source Voltage	± 30	
T_J	Maximum Junction Temperature	150	$^\circ\text{C}$
T_{STG}	Storage Temperature Range	-55 to 150	$^\circ\text{C}$
I_S	Diode Continuous Forward Current	11 ^a	A
I_{DP}^b	Pulse Drain Current Tested	$T_C=25^\circ\text{C}$	44 ^a
I_D	Continuous Drain Current	$T_C=25^\circ\text{C}$	11 ^a
		$T_C=100^\circ\text{C}$	7 ^a
P_D	Maximum Power Dissipation for TO-220/TO-251	$T_C=25^\circ\text{C}$	113
		$T_C=100^\circ\text{C}$	45
P_D	Maximum Power Dissipation for TO-220FP	$T_C=25^\circ\text{C}$	31
		$T_C=100^\circ\text{C}$	12.5
$R_{\theta JC}$	Thermal Resistance-Junction to Case for TO-220/TO-251	1.1	$^\circ\text{C}/\text{W}$
$R_{\theta JC}$	Thermal Resistance-Junction to Case for TO-220FP	4	
$R_{\theta JA}$	Thermal Resistance-Junction to Ambient	62.5	
Drain-Source Avalanche Ratings			
dv/dt^c	MOSFET dv/dt ruggedness	50	V/ns
E_{AS}^d	Avalanche Energy, Single Pulsed	144	mJ
I_{AR}^e	Avalanche Current	1.9	A
E_{AR}^e	Repetitive Avalanche Energy	0.34	mJ

Note a : limited by maximum junction temperature.

Note b : Pulse width limited by safe operating area.

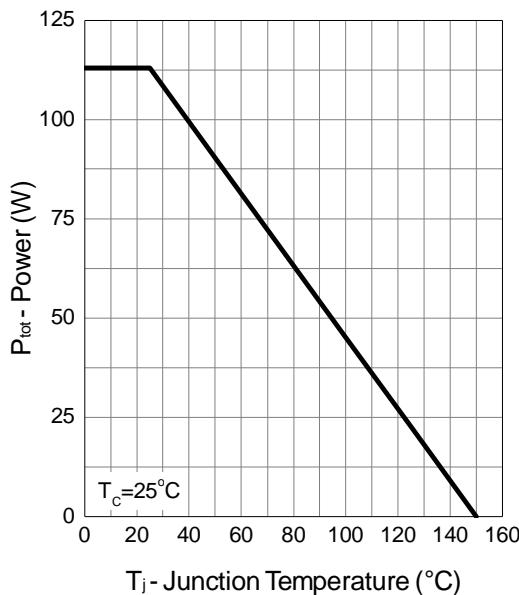
Note c : $V_{DS}=480\text{V}$, $I_D=11\text{A}$.

Note d : $I_D=1.9\text{A}$, $V_{DD}=50\text{V}$, $T_j=25^\circ\text{C}$.

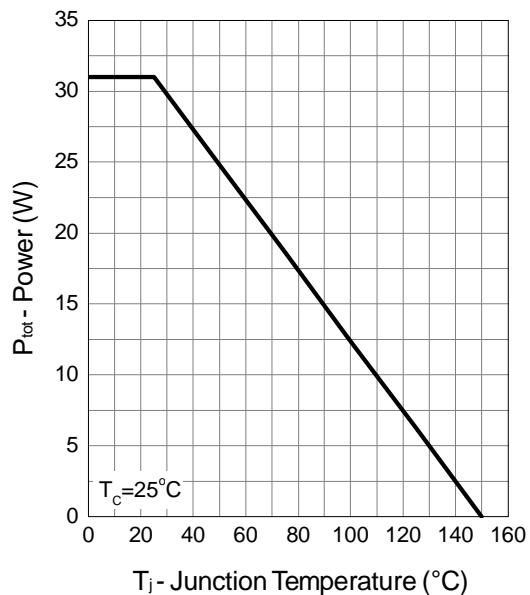
Note e : Repetitive Rating : Pulse width limited by maximum junction temperature.

Typical Operating Characteristics

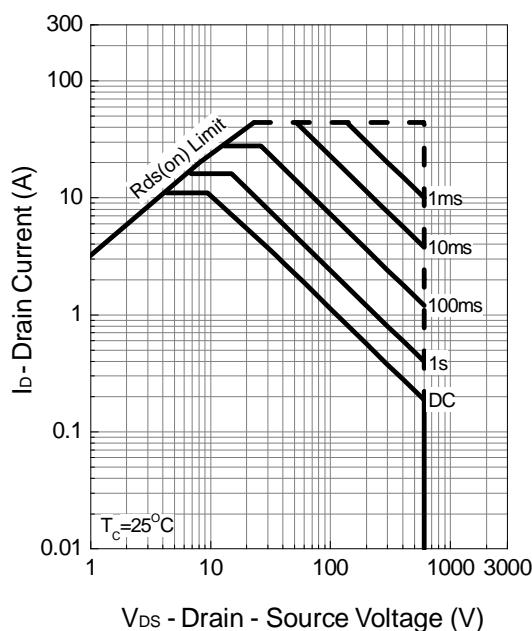
Power Dissipation : TO-220/TO-251



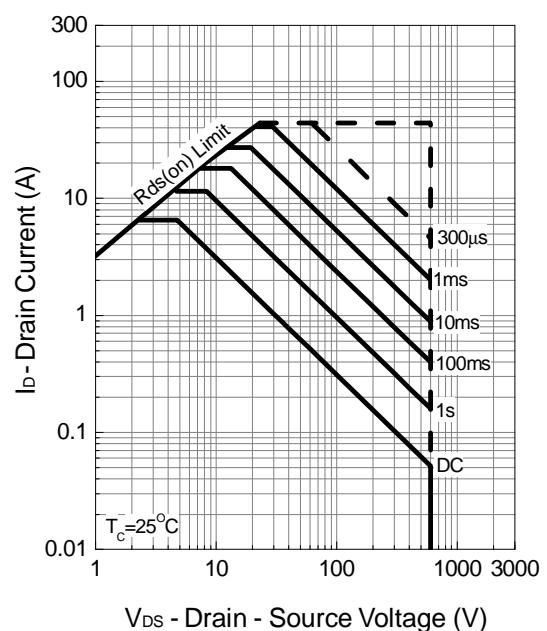
Power Dissipation : TO-220FP



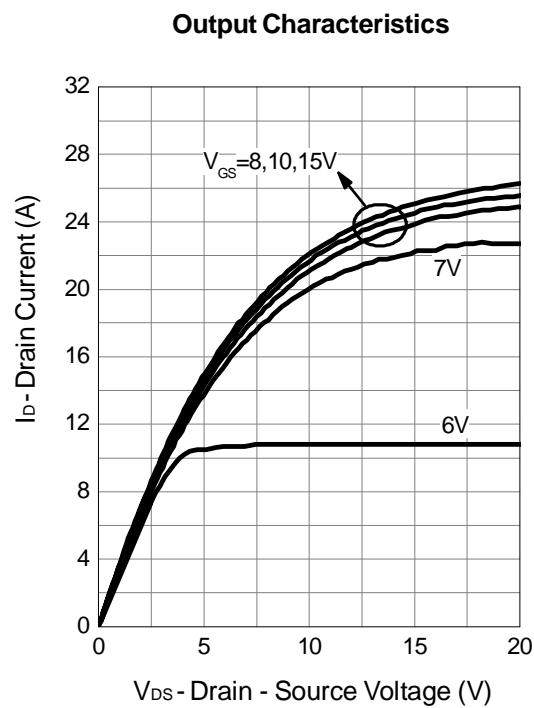
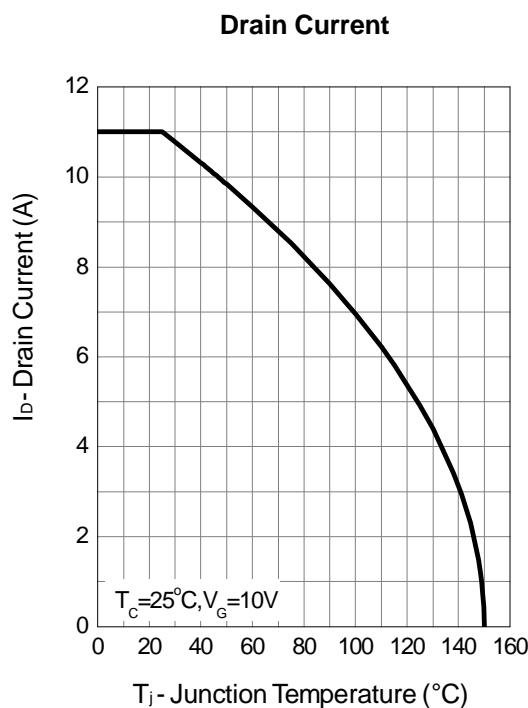
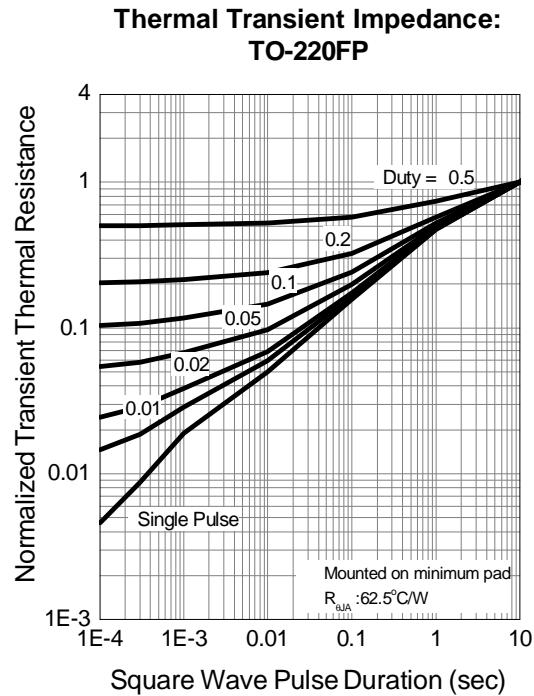
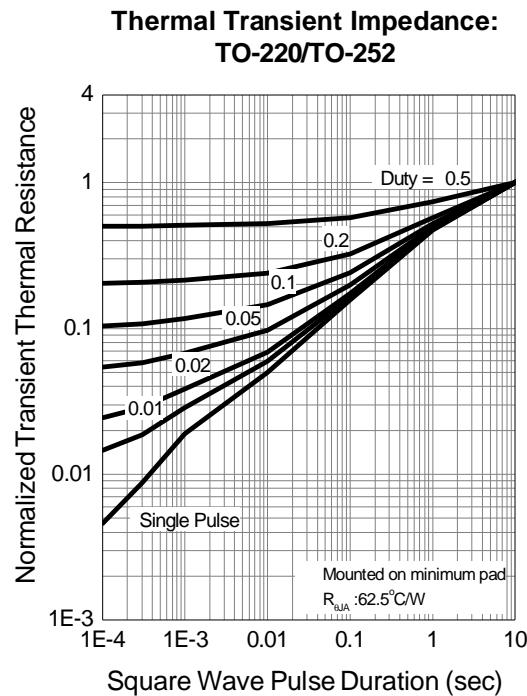
Safe Operation Area : TO-220/TO-251



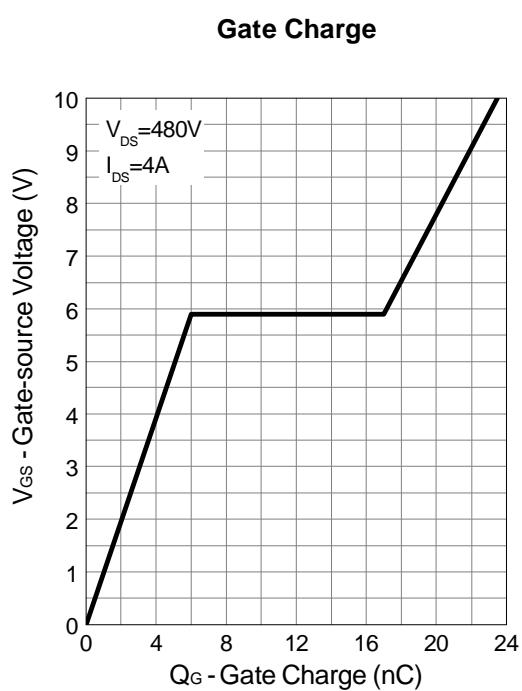
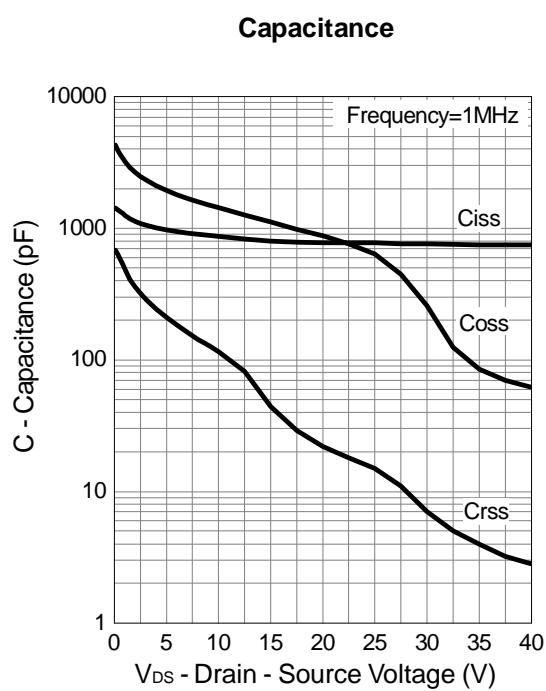
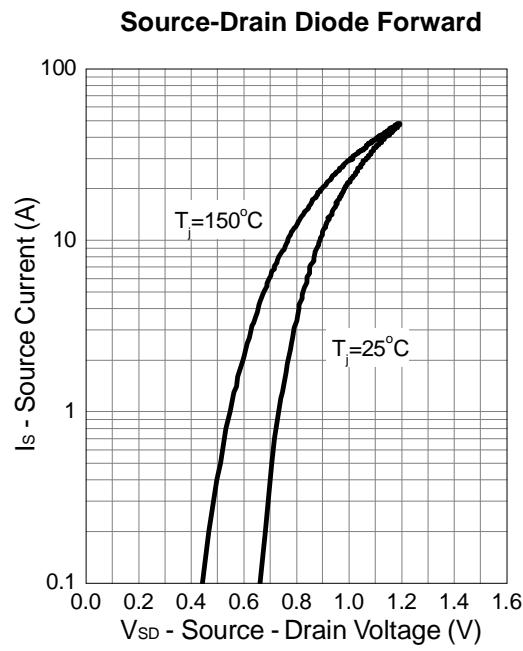
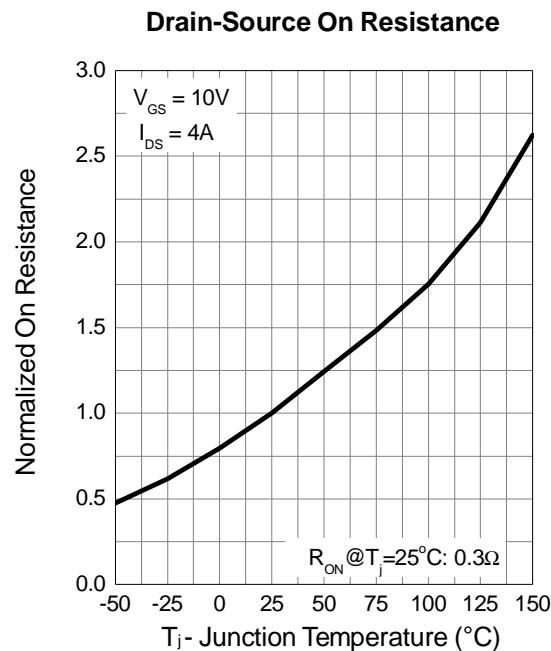
Safe Operation Area : TO-220FP



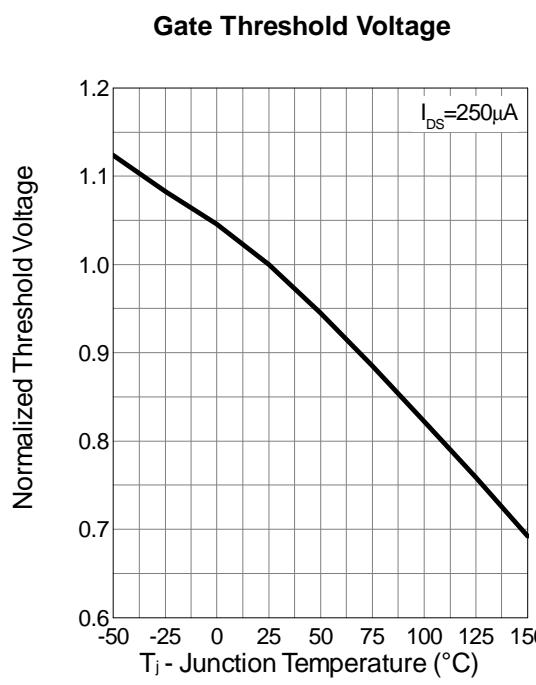
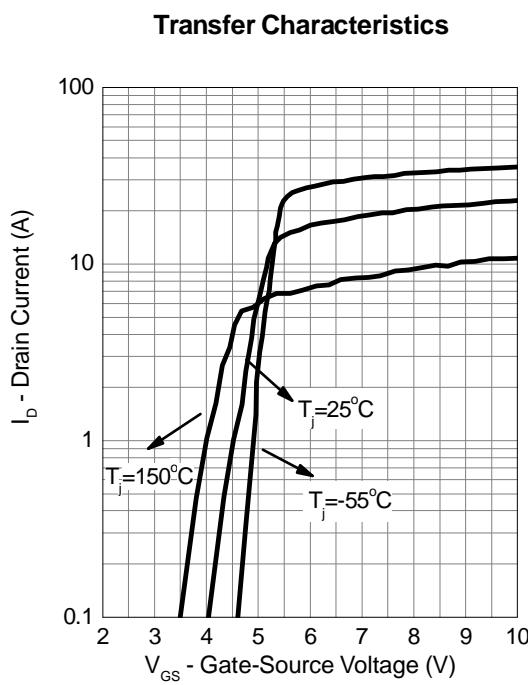
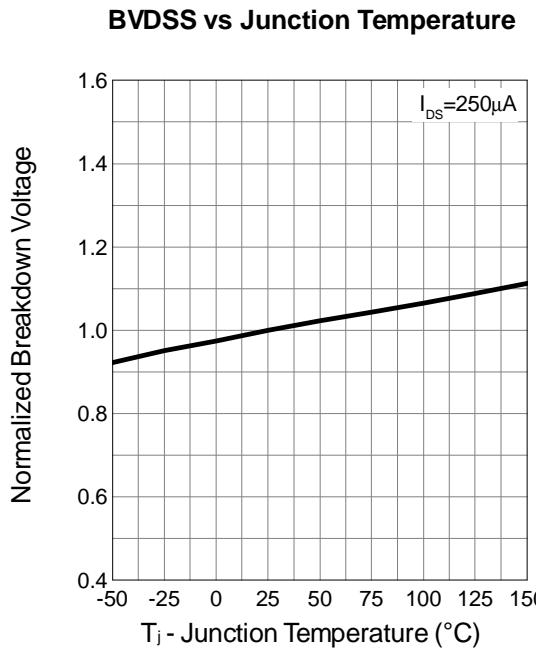
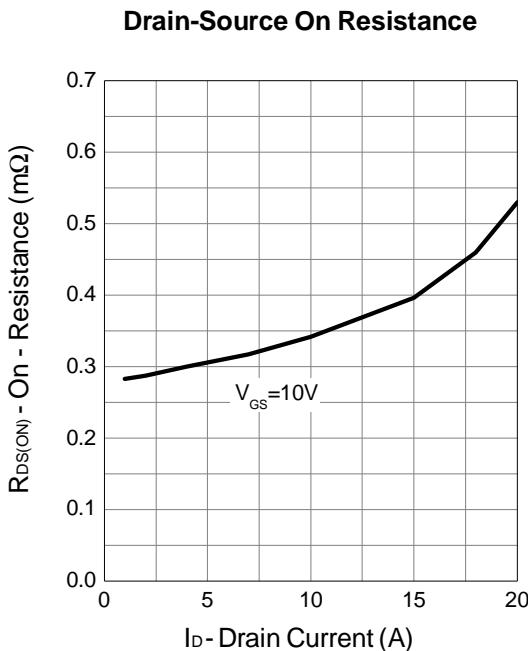
Typical Operating Characteristics (Cont.)



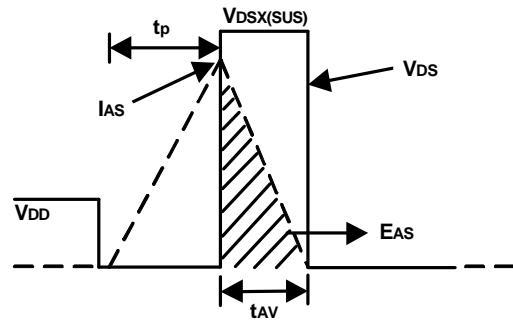
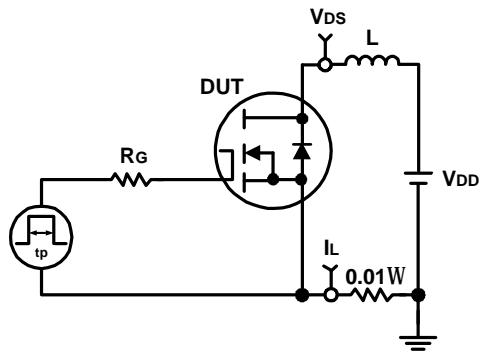
Typical Operating Characteristics (Cont.)



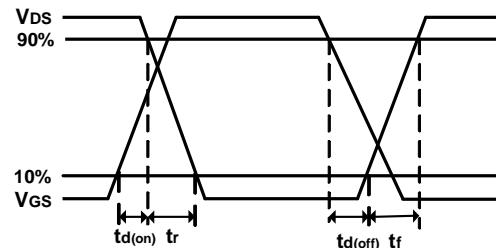
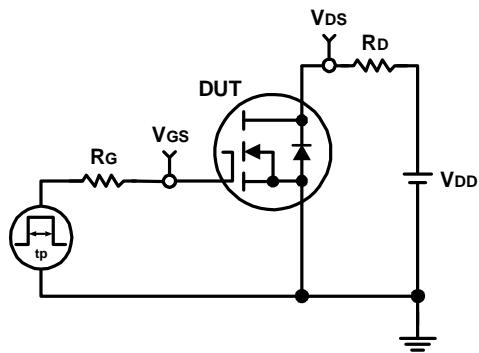
Typical Operating Characteristics (Cont.)



Avalanche Test Circuit and Waveforms



Switching Time Test Circuit and Waveforms



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Classification Profile

